Supporting Information for

Gallium(III) Tetraphenylporphyrinates Containing Hydrosulfide and Thiolate Ligands: Structural Models for Sulfur-Bound Iron(III) Hemes

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Figure S1. 500 MHz ¹H NMR spectrum of [Ga(SH)(TPP)] in benzene- $d_6(s)$. Asterisks denote peaks due to residual toluene and pentane from recrystallization.



Figure S2. 500 MHz ¹H NMR spectrum of [Ga(SEt)(TPP)] in benzene- d_6 (s).



Figure S3. 500 MHz ¹H NMR spectrum of [Ga(SPh)(TPP)] in benzene- d_6 (s). Asterisk denotes peak due to water from the NMR solvent.



Figure S4. 500 MHz ¹H NMR spectrum of $[Ga(SSi^iPr_3)(TPP)]$ in benzene- d_6 (*s*). Asterisk denotes peak due to water from the NMR solvent.



Figure S5. 500 MHz ¹H NMR spectrum of the mixture obtained upon mixing [Ga(SH)(TPP)] with 1.5 equivalents of $(H{Et_2O}_2)[B(3,5-{CF_3}_2C_6H_3)_4]$ ("HBAr^f₄") in dichloromethane-*d*₂ (*s*). Inset in black shows expansion of the aromatic region. Inset in red displays the spectrum of free H₂S_(g) recorded in dichloromethane-*d*₂. Inset in green displays the upfield region of the spectrum for [Ga(SH)(TPP)] in dichloromethane-*d*₂ prior to addition of HBAr^f₄. Asterisk denotes small amount of benzene from purification.



Figure S6. Electronic absorbance spectrum of [Ga(SH)(TPP)] in toluene.



Figure S7. Electronic absorbance spectrum of [Ga(SEt)(TPP)] in toluene.



Figure S8. Electronic absorbance spectrum of [Ga(SPh)(TPP)] in toluene.



Figure S9. Electronic absorbance spectrum of [Ga(SSi^{*i*}Pr₃)(TPP)] in toluene.



Figure S10. Thermal ellipsoid drawing (30%) of [Ga(SH)(TPP)].



Figure S11. Thermal ellipsoid drawing (50%) of [Ga(SEt)(TPP)] toluene. Minor components of the disorder omitted for clarity.



Figure S12. Thermal ellipsoid drawing (50%) of [Ga(SPh)(TPP)] toluene. Minor components of the disorder omitted for clarity.

Compound	[Ga(SH)(TPP)]	[Ga(SEt)(TPP)]	[Ga(SPh)(TPP)]
Empirical formula	C44H29GaN4S	$C_{46}H_{33}GaN_4S \cdot C_7H_8$	$C_{50}H_{33}GaN_4S\cdot C_7H_8$
Formula weight (g/mol)	715.49	1112.14	883.75
Temperature (K)	293(2)	98(2)	98(2)
Crystal system, space group	Monoclinic, $P2_1/n$	Monoclinic, <i>Pc</i> ^a	Triclinic, P1 ^b
Unit cell dimensions (Å)	a = 10.253(4) b = 16.179(7) c = 21.076(9)	a = 10.9029(19) b = 15.445(3) c = 12.296(2)	a = 10.4828(19) b = 11.1917(18) c = 11.492(2)
Onit cen unitensions (A)	$\beta = 90.460(11)$	$\beta = 102.636(7)$	$\alpha = 109.728(8)$ $\beta = 104.749(7)$ $\gamma = 109.738(8)$
Volume (Å ³)	3496(3)	2020.5(6)	1086.3(3)
Ζ	4	2	1
Calculated density (g/cm ³)	1.359	1.327	1.351
Absorption coefficient (mm ⁻¹)	0.885	0.774	0.726
F(000)	1472	837	458
Crystal size (mm)	$0.2\times0.2\times0.2$	$0.2\times0.2\times0.2$	$0.4\times0.3\times0.2$
Θ range	2.202 to 25.050°	3.116 to 24.550°	3.050 to 25.048°
Limiting indices	$-12 \le h \le 7,$ $-19 \le k \le 9,$ $-22 \le l \le 25$	$-11 \le h \le 12,$ $-18 \le k \le 17,$ $-14 \le l \le 13$	$-12 \le h \le 12,$ $-13 \le k \le 13,$ $-13 \le l \le 13$
Reflections collected / unique	$\frac{11910 / 6114}{[R_{int} = 0.0792]}$	10559 / 5129 [R _{int} = 0.0748]	6839 / 5491 [R _{int} = 0.0327]
Completeness to Θ	98.9%	99.6%	99.8%
Absorption correction	multi-scan ABSCOR	multi-scan ABSCOR	multi-scan ABSCOR
Min. and max transmission	0.506 and 1.000	0.311 and 0.910	0.797 and 1.000
Data / restraints / parameters	6114 / 0 / 454	5129 / 2 / 493	5491 / 3 / 529
Goodness-of-fit on F ²	1.047	0.968	1.003
Final R indices $[I > 2\sigma(I)]$	$R_1 = 0.0656,$ $wR_2 = 0.1323$	$R_1 = 0.0951,$ $wR_2 = 0.2203$	$R_1 = 0.0521,$ $wR_2 = 0.1277$
R indices (all data)	$R_1 = 0.1050,$ $wR_2 = 0.1568$	$R_1 = 0.0990,$ $wR_2 = 0.2233$	$R_1 = 0.0538,$ $wR_2 = 0.1296$
Largest diff. peak and hole $(e \cdot A^{-3})$	0.416 and -0.395	0.702 and -0.784	0.795 and -0.774

Table S1. Crystallographic data and refinement parameters for [Ga(SR)(TPP)].§

[§]Refinement method was full-matrix least-squares on F²; wavelength = 0.71073 Å. R₁ = $\sum ||F_o| - |F_c|| / \sum |F_o|;$ wR₂ = { $\sum [w(F_o^2 - F_c^2)^2] / \sum [w(F_o^2)^2]$ }^½.

^aThis molecule crystallizes in space group $P2_1/c$. However, due to disorder between the ethanethiolate and toluene molecules (70/30%) in the crystal lattice, the structure refined better in space group Pc.

^bThere is a positional disorder (65/35%) between benzenethiolate and a toluene molecule. Several attempts to transform the space group from P1 to $P\overline{1}$ resulted in an overall poor refinement of the structure. The structure refined the best in space group P1, however, the correct space group should be $P\overline{1}$.